

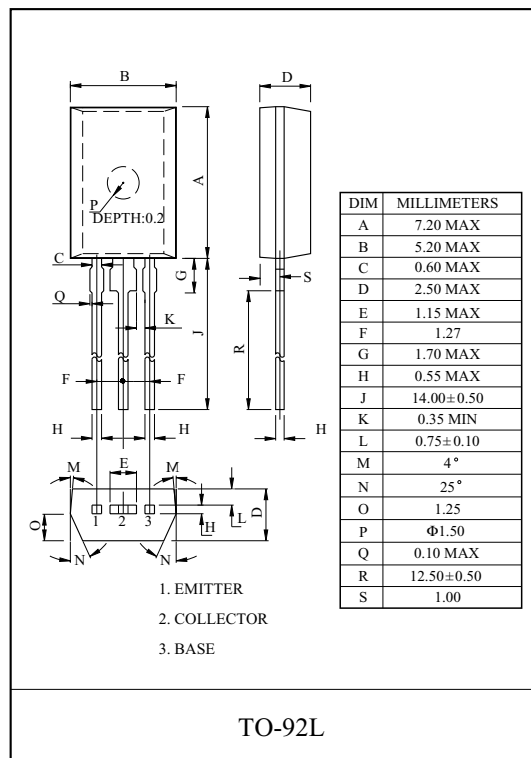
HIGH VOLTAGE APPLICATION.

FEATURE

- Complementary to KTC1027.

MAXIMUM RATING (Ta=25 °C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V_{CBO}	-120	V
Collector-Emitter Voltage	V_{CEO}	-120	V
Emitter-Base Voltage	V_{EBO}	-5	V
Collector Current	I_C	-800	mA
Emitter Current	I_E	800	mA
Collector Power Dissipation	P_C	1	W
Junction Temperature	T_j	150	°C
Storage Temperature Range	T_{stg}	-55 ~ 150	°C



ELECTRICAL CHARACTERISTICS (Ta=25 °C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	I_{CBO}	$V_{CB}=-120V, I_E=0$	-	-	-100	nA
Emitter Cut-off Current	I_{EBO}	$V_{EB}=-5V, I_C=0$	-	-	-100	nA
Collector-Emitter Saturation Voltage	$V_{(BR)CEO}$	$I_C=-10mA, I_B=0$	-120	-	-	V
Emitter-Base Breakdwon Voltage	$V_{(BR)EBO}$	$I_E=-1mA, I_C=0$	-5	-	-	V
DC Current Gain	$h_{FE}(\text{Note})$	$V_{CE}=-5V, I_C=-100mA$	80	-	240	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=-500mA, I_B=-50mA$	-	-	-1.0	V
Base-Emitter Voltage	V_{BE}	$V_{CE}=-5V, I_C=-500mA$	-	-	-1.0	V
Transition Frequency	f_T	$V_{CE}=-5V, I_C=-100mA$	-	120	-	MHz
Collector Output Capacitance	C_{ob}	$V_{CB}=-10V, I_E=0, f=1MHz$	-	-	40	pF

Note : h_{FE} Classification O:80 ~ 160, Y:120 ~ 240

